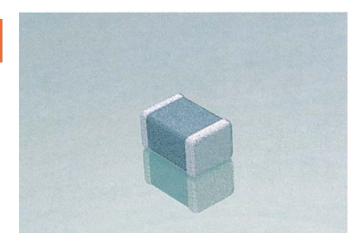
COG (NPO) Dielectric

General Specifications

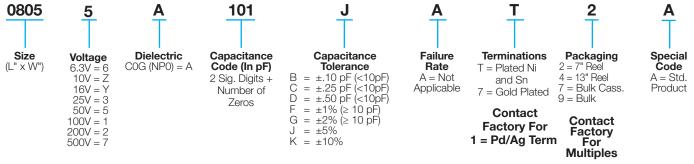




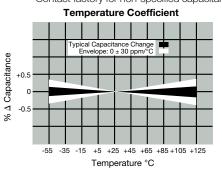
COG (NP0) is the most popular formulation of the "temperature-compensating," EIA Class I ceramic materials. Modern COG (NP0) formulations contain neodymium, samarium and other rare earth oxides.

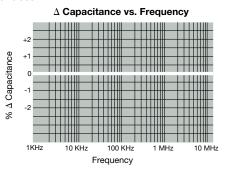
COG (NP0) ceramics offer one of the most stable capacitor dielectrics available. Capacitance change with temperature is 0 $\pm 30 \mathrm{ppm/^\circ C}$ which is less than $\pm 0.3\%$ $\Delta\mathrm{C}$ from -55°C to +125°C. Capacitance drift or hysteresis for COG (NP0) ceramics is negligible at less than $\pm 0.05\%$ versus up to $\pm 2\%$ for films. Typical capacitance change with life is less than $\pm 0.1\%$ for COG (NP0), one-fifth that shown by most other dielectrics. COG (NP0) formulations show no aging characteristics.

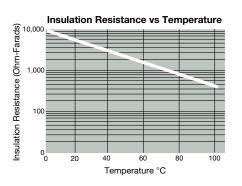
PART NUMBER (see page 2 for complete part number explanation)



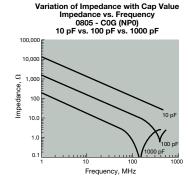
NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

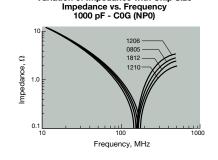




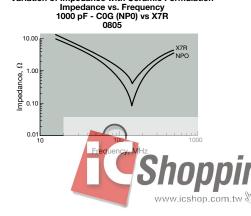


Variation of Impedance with Ceramic Formulation





Variation of Impedance with Chip Size



C0G (NP0) Dielectric

Specifications and Test Methods



	ter/Test	NP0 Specification Limits	Measuring Conditions						
Operating Temp		-55°C to +125°C	Temperature Cycle Chamber						
Capac	itance	Within specified tolerance	Freq.: 1.0 MHz ± 10% for cap ≤ 1000 pF						
)	<30 pF: Q≥ 400+20 x Cap Value	1.0 kHz ± 10% for cap > 1000 pF						
	<u> </u>	≥30 pF: Q≥ 1000	Voltage: 1.0Vrms ± .2V						
Insulation	Resistance	100,000MΩ or 1000MΩ - μF,	Charge device with rated voltage for						
		whichever is less	60 ± 5 secs @ room temp/humidity						
Dielectric	Strength	No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.						
	Appearance	No defects	Deflection: 2mm						
Resistance to	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Test Time: 30 seconds						
Flexure Stresses	Q	Meets Initial Values (As Above)	V						
	Insulation Resistance	≥ Initial Value x 0.3	90 r						
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.						
	Appearance	No defects, <25% leaching of either end terminal							
	Capacitance Variation	\leq ±2.5% or ±.25 pF, whichever is greater	Dip device in eutectic :	solder at 260°C for 60					
Resistance to Solder Heat	Q	Meets Initial Values (As Above)	seconds. Store at room hours before measurin	temperature for 24 ± 2					
	Insulation Resistance	Meets Initial Values (As Above)							
	Dielectric Strength	Meets Initial Values (As Above)							
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes					
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp	≤ 3 minutes					
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes					
o.i.ook	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes					
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and measure after 24 hours at room temperature						
	Appearance	No visual defects							
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twice rated voltage in test chamber set at 125°C ± 2°C for 1000 hours (+48, -0). Remove from test chamber and stabilize at room temperature for 24 hours before measuring.						
Load Life	Q (C=Nominal Cap)	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C							
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)							
	Dielectric Strength	Meets Initial Values (As Above)							
	Appearance	No visual defects							
	Capacitance Variation	\leq ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber set at 85°C ± 2°C/85% ± 5% relative humidity for 1000 hours (+48, -0) with rated voltage applied. Remove from chamber and stabilize at room temperature for 24 ± 2 hours before measuring.						
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C							
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)							
	Dielectric Strength	Meets Initial Values (As Above)							





C0G (NP0) Dielectric





PREFERRED SIZES ARE SHADED

					ED										
SIZE	01005	0201	0402		0603			0805	1206						
Soldering	Reflow Only	Reflow Only	Reflow/Wave	e R	Reflow/Wave		F	Reflow/Wave	Reflow/Wave						
Packaging mm	All Paper 0.40 ± 0.02	All Paper 0.60 ± 0.03	All Paper 1.00 ± 0.10		All Paper 1.60 ± 0.15		Pap	per/Embossed 2.01 ± 0.20		Paper/Embossed					
(L) Length (in.)	(0.016 ± 0.0008)	(0.024 ± 0.001)	(0.040 ± 0.004)) (0	(0.063 ± 0.006)			0.079 ± 0.008)	3.20 ± 0.20 (0.126 ± 0.008)						
(W) Width mm (in.)	0.20 ± 0.02 (0.008 ± 0.0008)	0.30 ± 0.03 (0.011 ± 0.001)	0.50 ± 0.10 (0.020 ± 0.004)) (0	0.81 ± 0.15 0.032 ± 0.006)		(0	1.25 ± 0.20 0.049 ± 0.008)	1.60 ± 0.20 (0.063 \pm 0.008)						
(t) Terminal mm	0.10 ± 0.04 (0.004 ± 0.016)	0.15 ± 0.05 (0.006 ± 0.002)	0.25 ± 0.15 (0.010 ± 0.006)		0.35 ± 0.15 (0.014 ± 0.006)			0.50 ± 0.25 0.020 ± 0.010)	0.50 ± 0.25 (0.020 ± 0.010)						
WVDC	16	25 50				100	16 25	50 100	200	16	25	50	100	200	500
Cap 0.5 (pF) 1.0	В	A A		C G G		G G	J J	J J	J	J	J	J	J J	J	J
1.2 1.5	B B	A A		C G G		G G	J J	JJ	J	J	J	J	J J	J	J J
1.8	В	A A	C C	C G	G G	G	J J	J J	J	J	J	J	J	J	J
2.2 2.7	B B	A A		C G G		G G	JJ	JJJ	J	J	J	J	J J	J	J
3.3 3.9	B B	A A	C C	C G G		G G	J J	J J	J	J	J	J	J J	J	J
4.7	В	A A	C C	C G	G G	G	J J	J	J	J	J	J	J	J	J J
5.6 6.8	B B	A A	C C C	C G G		G G	J J	JJJ	J	J	J	J	J J	J	J J
8.2	В	A A	C C	C G	G G	G	J J	J J	J	J	J	J	J	J	J
10 12	B B	A A		C G G	G G	G G	J J	JJJ	J	J	J	J	J	J	J
15 18	B B	A A	C C	C G C		G G	J J	J J	J	J	J	J	J J	J	J
22	В	A A	CC	C G	G G	G	J J	J J	J	J	J	J	J	J	J
33		A A	C C	C G G		G G	J J	J J	J	J	J	J	J	J	J
39 47		A A	C C	C G G		G G	J J	JJJ	J	J	J	J	J J	J	J J
56		А	C C	C G	G G	G	J J	J J	J	J	J	J	J	J	J
68 82		A A		C G G		G G	JJ	JJJ	J	J	J	J	J J	J	J
100		А	C C	C G G	G G	G G	J J	J J	J	J	J	J	J	J	J
120 150			C C	C G	G G	G	J J	J J	J	J	J	J	J J	J	J
180 220				C G G		G G	J J	JJJ	J	J	J	J	J J	J	J M
270			C C	C G C		G G	J J	J J	M	J	J	J	J	J	M
390			C C	C G	G G	G	J J	JJ	M	J	J	J	J	J	М
470 560			CC	C G G	G G		J J	J J	M	J	J	J	J	J	M
680				G	G G		J J	J J		J	J	J	J	J	Р
820 1000				G	G G		J J	J J		J	J	J	J	M Q	
1200 1500							JJ	J		J	J	J	J M	Q Q	
1800							J J	J		J	J	М	М		
2200 2700							J J	N N		J	J	M M	P P		
3300 3900							J J			J	J	M M	P P		
4700							J J		1	J	J	М	P		
5600 6800		ı l								M	J M	M			
8200 Cap 0.010			W	-		\dashv			+	M M	M	-+			
(μF) 0.012			\	-											
0.015 0.018	 		<i></i>	` 		\dashv			+		+	+			
0.022 0.027		-	₹v												
0.033		· ·	<u> </u>			\dashv			1						
0.039 0.047															
0.068 0.082						\Box									
0.1															
SIZE	25 01005	50 16 0201	25 50 0402	16 25	50 100 0603	16	25 50	100 200 0805	16	25	50	100 120	200)6	500	
Letter	A B	C C	E G	i J	K	M	l N	P	Q	X		Y	Z		
Max.	0.22	0.56	0.71 0.9	0.94	1.02	1.27	1.40	1.52	1.78	2.29	_	.54	2.79	,	
Thickness (0.	.013) (0.009	9) (0.022) PAPER	(0.028) (0.0	35) (0.037)	(0.040)	(0.050	<u>, </u>	(0.060) EMBOSSED	(0.070)	(0.090)	0.	TUO	(0.110)	
		PAPEK						FINIDO92ED							

C0G (NP0) Dielectric





PREFERRED SIZES ARE SHADED

FREFERNED SIZES ARE SHADED													П		ПП						
													Ш								
SIZ	Έ	1210			1812					1825			2220			2225					
Solde		Reflow Only Paper/Embossed				Reflow Only					Reflow Only			Reflow Only			Reflow Only				
Packa	ging mm	3.20 ± 0.20					All Embossed 4.50 ± 0.30					All Embossed 4.50 ± 0.30			All Embossed 5.70 ± 0.40			All Embossed 5.72 ± 0.25			
(L) Length	(in.)	(0.126 ± 0.008) 2.50 ± 0.20					(0.177 ± 0.012) 3.20 ± 0.20					(0.	177 ± 0.01 6.40 ± 0.40	12)	(0.225 ± 0.016) 5.00 ± 0.40			(0.225 ± 0.010) 6.35 ± 0.25			
(W) Width	mm (in.)	(0.098 ± 0.008)					(0.126 ± 0.008)					(0.	252 ± 0.01	16)	(0.197 ± 0.016)			(0.250 ± 0.010)			
(t) Terminal	mm (in.)				0.61 ± 0.36 (0.024 ± 0.014)						0.61 ± 0.36 024 ± 0.01		0.64 ± 0.39 (0.025 ± 0.015)			0.64 ± 0.39 (0.025 ± 0.015)					
	WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	50	100	200	
Cap (pF)	0.5 1.0																				
u- 7	1.2																				
	1.5 1.8															+	I	ı	l	I	
	2.2																	>	<\widety	<u></u>	
	2.7 3.3															┼ ~	حکار ۲	<	$\overline{}$	\ ^	
	3.9																	7)	سلر	1	
	4.7 5.6															+		<u> </u>			
	6.8 8.2																	T'			
	10					J										<u> </u>	1	l			
	12 15					J															
	18					J															
	22 27					J															
	33 39					J															
	47					J															
	56 68					J															
	82					J															
	100 120					J															
	150					J															
	180 220					J															
	270 330					J															
	390					М															
	470 560	J	J	J	J	M															
	680	J	J	J	J	M															
	820 1000	J	J	J	J	M	K	K	K	K	M	М	M	М				М	М	Р	
	1200 1500	J J	J	J	M M	M M	K K	K K	K K	K K	M M	M M	M M	M M				M M	M M	P P	
	1800	J	J	J	М	IVI	K	K	K	K	М	М	М	М				М	М	Р	
	2200 2700	J J	J	J	QQ		K K	K	K K	K P	P Q	M M	M M	M M				M M	M M	P P	
	3300	J	J	J			K	K	K	Р	Q	М	М	М			X	М	М	P	
	3900 4700	J J	J	M M			K K	K K	K K	P P	Q Q	M M	M M	M M	Х	X	X	M M	M M	P P	
	5600 6800	J	J				K	K	M	P X	Х	М	M	M M	X	X	Х	M	M	P P	
	8200	J	J				K K	K M	M M	^		M M	M M	IVI	X X	X	X	M M	M M	Р	
Cap (µF)	0.010 0.012	J	J				K K	M M	М			M M	M M		X	X	X	M M	M M	P P	
V=: /	0.015						М	М				М	М		Χ	Х	Х	М	М	Υ	
	0.018 0.022						M M	M M				P P	М		X X	X	Х	M M	M Y	Y	
	0.027						M M	M M				P P			Х	X		P P	Υ	Υ	
	0.039						М	M				Р			X Y			Р			
	0.047						M M	M M				Р			Υ			P P			
	0.082						M	M										Q			
	0.1 WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	Q 50	100	200	
	SIZE	1210					1812					1825			2220			2225			
Letter	А	С		Е	G	· ·		K	М	N		Р	Q)		Υ	Z				
Max. Thickness	0.33 (0.013)	(0.0)		0.71 0.028)	0.90 (0.035)	0.0)		1.02 (0.040)	1.27 (0.050)	(0.0		1.52 (0.060)	1.78 (0.070)		29)90)	2.54 (0.100)	2.79))			
	(5.0.0)										EMBOSSED										

